# VS-SC240FA65



Vishay Semiconductors

## SOT-227 Silicon Carbide Schottky Barrier Diode, 650 V, 240 A



PRIMARY CHARACTERISTICS						
V <sub>R</sub>	650 V					
V <sub>F</sub> (typical) at 120 A, per diode	1.40 V					
Q <sub>C</sub> (typical), per diode	328 nC					
$I_{F(DC)}$ per module at $T_C = 117 \text{ °C}$	240 A					
Туре	Modules - diode, SiC Schottky					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

#### FEATURES

Virtually no recovery tail and no switching losses



COMPLIANT

- Majority carrier diode using Schottky technology on SiC wide band gap material
- Improved  $V_{\rm F}$  and efficiency by thin wafer technology
- High speed switching, low switching losses
- Positive temperature coefficient, for easy paralleling
- Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V <sub>R</sub>		650	V		
Continuous forward current per diode	I <sub>F</sub>	T <sub>C</sub> = 117 °C	120	^		
Single pulse forward current per diode	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 6 ms square pulse	675	A		
Maximum power dissipation per module	PD	T <sub>C</sub> = 117 °C	483	W		
RMS isolation voltage	V <sub>ISOL</sub>	Any terminal to case, t = 1 min	2500	V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	$V_{BR}$	I <sub>R</sub> = 600 μA	650	-	-	
Forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 120 A	-	1.40	1.61	V
		I <sub>F</sub> = 120 A, T <sub>J</sub> = 150 °C	-	1.64	-	
		V <sub>R</sub> = 650 V	-	5.2	240	
Reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 650 V	-	18.2	-	μA
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = 650 V	-	26.6	-	
Junction capacitance	CT	V <sub>R</sub> = 650 V, f = 1 MHz	-	479	-	pF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> = 400 V	-	328	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance junction to case, per diode	P		-	-	0.25	
Thermal resistance junction to case, per module	R <sub>thJC</sub>		-	-	0.12	°C/W
Thermal resistance case to heatsink, per module	R <sub>thCS</sub>	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)
		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT	Г-227	

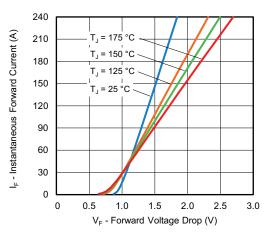


Fig. 1 - Typical Forward Voltage Drop Characteristics

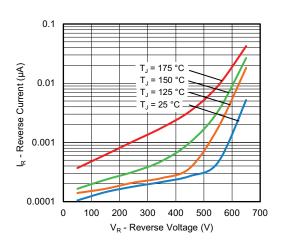


Fig. 2 - Typical Values Reverse Current vs. Reverse Voltage

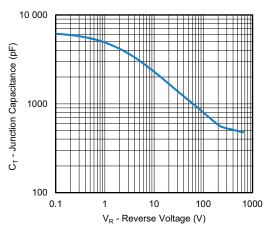


Fig. 3 - Junction Capacitance vs. Reverse Voltage

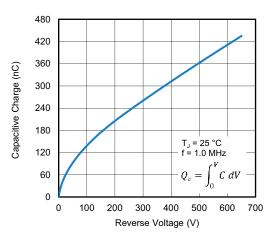


Fig. 4 - Typical Capacitive Charge vs. Reverse Voltage

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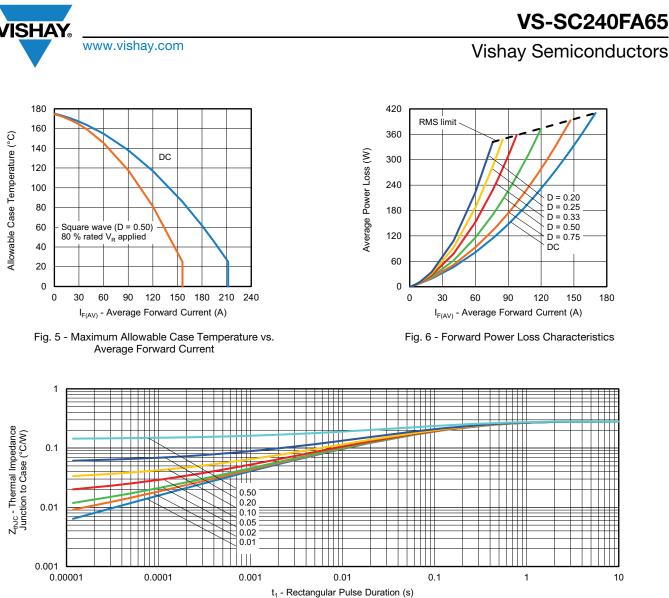
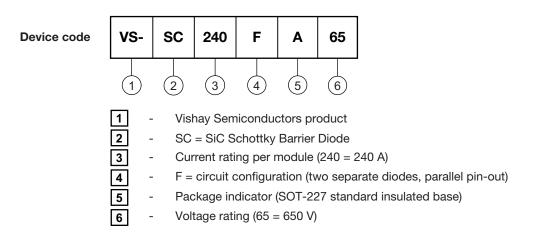


Fig. 7 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**



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### **VS-SC240FA65**

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CIRCUIT CONFI	CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two separate diodes, parallel pin-out	F	Lead Assignment 4 1 1 1 1 1 1 1 1 1 1 1 1 1				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95423					
Packaging information	www.vishay.com/doc?95425				

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SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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